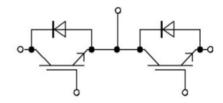


C1 series package: 1200V 100A IGBT module

Datasheet





Equivalent Circuit Schematic

Features:

- IGBT 1200V/100A
- Planar Field Stop Fast IGBT technology
- ullet $V_{\text{CE(sat)}}$ with positive temperature coefficient
- High RBSOA capability
- Low turn-off losses

Options:

 Pre-applied TIM (option +M01)

Typical Applications:

- Inductive Heating
- Welding
- High Frequency Switching Application



IGBT, Inverter / IGBT Maximum Rated Values

Collector-emitter Voltage	Tvj = 25°C	VCES	1200	V
Continuous DC Collector Current		ICnom	100	А
	Tc = 80°C, T _{vj max} = 150°C	Ic	107	Α
Repetitive Peak Collector Current	ICRM = 2 x Icnom	ICRM	200	А
Total Power Dissipation	Tc = 25°C, T _{vj max} = 150°C	Ptot	565	W
Gate-emitter Peak Voltage		VGES	±20	V

Characteristic Values				min.	typ.	max.	
Collector-emitter Saturation Voltage ¹⁾	Ic = 100A, VgE = 15V	T _{vj} = 25°C T _{vj} = 125°C T _{vj} = 150°C	VCEsat		2.50 3.00 3.10	3.00	٧
Gate Threshold Voltage	VCE = VGE, IC = 1mA, T _{vj} = 25	5°C	VGEth	5.0	6.0	7.0	V
Gate Charge	VgE = -8V/15V, VcE = 600V,	Tvj = 25°C	QG	_	0.30	-	μC
Internal Gate Resistor	Tvj = 25°C		RGint	_	8	-	Ω
Input Capacitance	Vce = 25V, Vge = 0V		Cies	-	4.35	-	nF
Reverse Transfer Capacitance	f = 100kHz, T _{vj} = 25°C		Cres	_	0.17	_	nF
Collector-emitter Cutoff Current	VcE = 1200V, VGE = 0V, Tvj =	= 25°C	ICES	_	_	1	μΑ
Gate-emitter Leakage Current	VCE = 0V, VGE = ±20V, Tvj = 2	25°C	IGES	-	-	±200	nA
Turn-on Delay Time, Inductive Load	Ic = 100A, VcE = 600V VGE = ±15V Rgon = 4.7Ω	T _{Vj} = 25°C T _{Vj} = 125°C T _{Vj} = 150°C	tdon	-	60 61 64	-	ns
Rise Time, Inductive Load	Ic = 100A, VcE = 600V VGE = ±15V Rgon = 4.7Ω	T _{vj} = 25°C T _{vj} = 125°C T _{vj} = 150°C	tr	-	45 51 53	-	ns
Turn-off Delay Time, Inductive Load	IC = 100A, VCE = 600V VGE = ± 15 V RGoff = 4.7Ω	Tvj = 25°C Tvj = 125°C Tvj = 150°C	t doff	-	197 231 246	-	ns
Fall Time, Inductive Load	IC = 100A, VCE = 600V VGE = ± 15 V RGoff = 4.7Ω	Tvj = 25°C Tvj = 125°C Tvj = 150°C	tf	-	18 24 28	-	ns
Turn-on Energy Loss per Pulse	IC = 100A, VCE = 600V, L_{σ} = 80nH, VGE = ±15V, RGon = 4.7 Ω	Tvj = 25°C Tvj = 125°C Tvj = 150°C	Eon	-	8.9 12.9 13.7	_	mJ
Turn-off energy Loss per Pulse	IC = 100A, VCE = 600V, L_{σ} = 80nH, VGE = ±15V RGoff = 4.7 Ω	Tvj = 25°C Tvj = 125°C Tvj = 150°C	Eoff	-	2.5 3.9 5.0	_	mJ

¹⁾ Terminal impedance is not included.



Thermal Resistance, Junction to Case	Per IGBT / IGBT	RthJC	I	0.22	ı	K/W
Temperature under Switching Conditions		Tvj op	-40		150	°C

Diode, Inverter Maximum Rated Values

Repetitive Peak Reverse Voltage	Tvj = 25°C	VRRM	1200	V
Continuous DC Forward Current		lF	100	А
Repetitive Peak Forward Current	ICRM = 2 x Ifnom	IFRM	200	А

Characteristic Values				min.	typ.	max.	
Forward Voltage	IF = 100A, VGE = 0V	Tvj = 25°C Tvj = 125°C Tvj = 150°C	VF		2.38 2.50 2.47	2.90	V
Peak Reverse Recovery Current	IF = 100A, VR = 600V -dir/dt = 21700A/usn (Tvj = 150°C) VGE = -15V		lгм	-	55 55 55	_	A
Recovery Charge	IF = 100A, VR = 600V -dir/dt = 1700A/usn (Tvj = 150°C) VGE = -15V		QR	ı	3.50 7.50 9.00	-	uC
Reverse Recovery Energy		Tvj = 25°C Tvj = 125°C Tvj = 150°C	Erec	-	2.50 4.20 4.80	-	mJ
Thermal Resistance, Junction to Case	Per Doide / Diode		RthJC		0.50	_	K/W
Temperature under Switching Conditions			Tvj op	-40		150	°C

Module

Isolation Test Voltage	RMS, f = 50Hz, t = 1min	VisoL	3.0	kV
Material of Module Baseplate			Cu	
Internal Isolation	(class 1, IEC 61140) Basic insulation (class 1, IEC 61140)		AL2O3	
Creepage Distance	Terminal to heatsink Terminal to terminal		17.0 20.0	mm
Clearance	Terminal to heatsink Terminal to terminal		17.0 9.5	mm
Comparative Tracking Index		СТІ	>200	

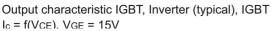


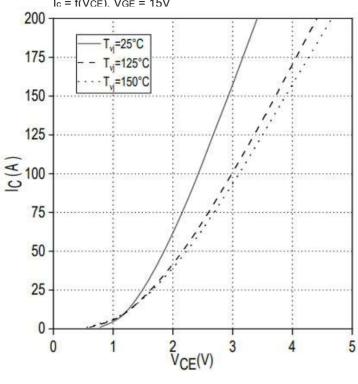
min. typ. max.

Thermal resistance, case to heatsink	per module λPaste = 1W/(m·K)/λgrease = 1W/(m·K)	RthCH		0.05		K/W
Stray Inductance Module		LsCE	-	30	-	nH
Module Lead Resistance, Terminals-Chip	Tc = 25°C, Per Switch	Rcc'+EE'	1	0.65	-	mΩ
Storage Temperature		Tstg	-40	_	125	°C
Modul MountingTorque	M5	М	4.0	_	6.0	Nm
Terminal MountingTorque	M6	М	3.0	_	6.0	Nm
Weight		G	-	145	-	g

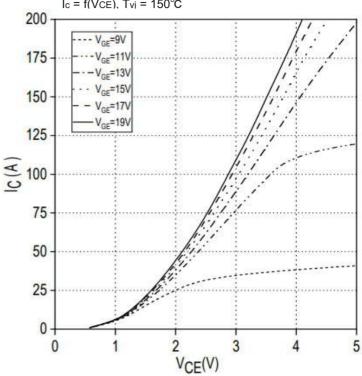


Circuit Diagram

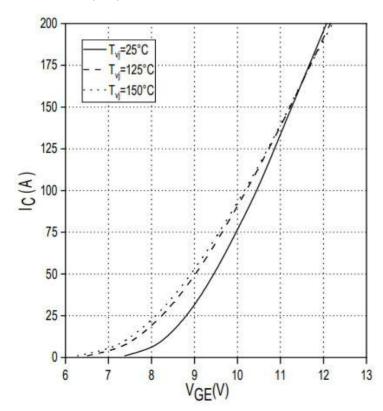




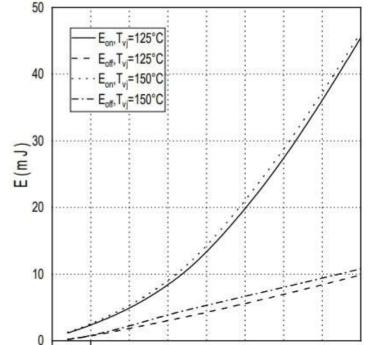
Output characteristic IGBT, Inverter (typical), IGBT $I_C = f(VCE)$, $T_{Vi} = 150^{\circ}C$



Transfer characteristic IGBT,Inverter(typical), IGBT $I_c = f(V_{GE})$, $V_{CE} = 20V$



Switching losses IGBT, Inverter (Typical), IGBT Eon = f(Ic), Eoff = f(Ic) VGE = $\pm 15V$, RGon = 4.7Ω , RGoff = 4.7Ω , VCE = 600V



0

25

50

75

100

IC(A)

125

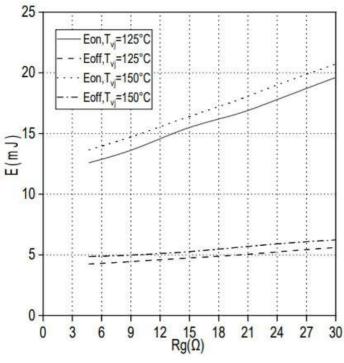
150

175

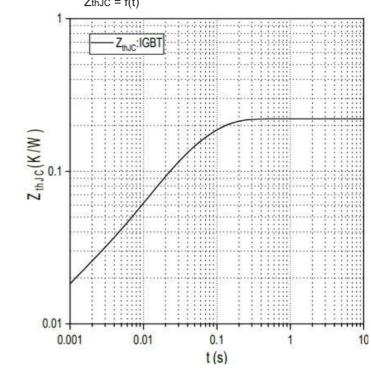
200



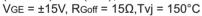
Switching losses IGBT, Inverter (typical), IGBT VGE = ±15V, IC = 100A, VCE = 600V

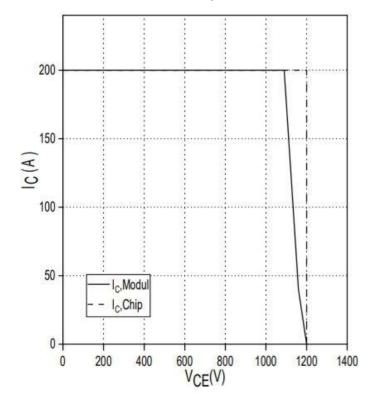


Transient thermal impedance IGBT, Inverter ZthJC = f(t)

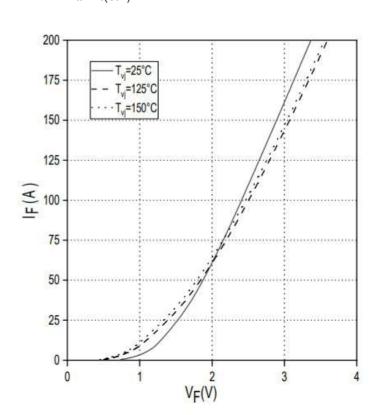


Reverse bias safe operating area IGBT, Inverter (RBSOA) Ic = f(VcE),

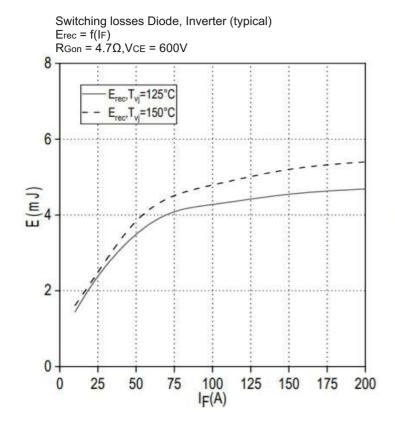


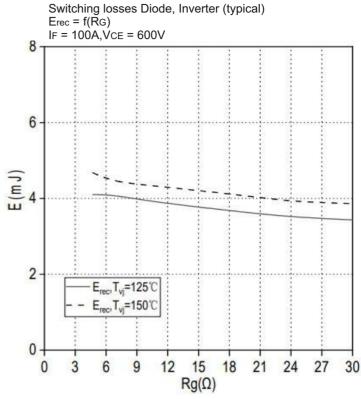


Forward characteristic of Diode, Inverter (typical) IF = f(VF)

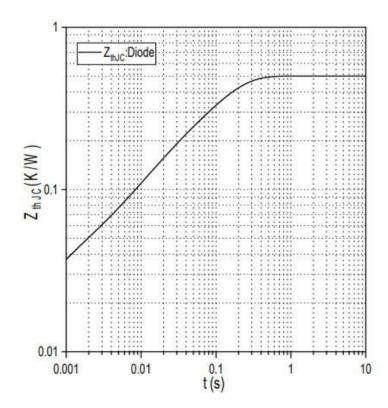




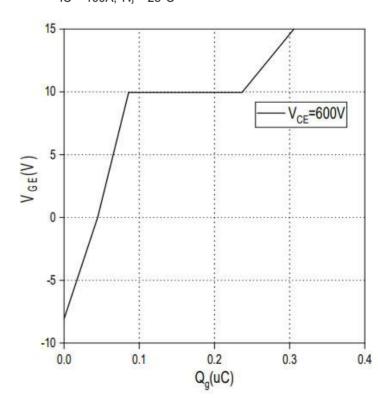




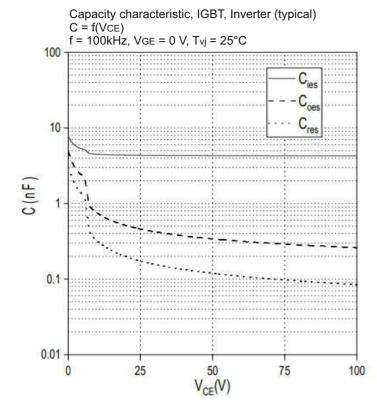
Transient thermal impedance Diode , Inverter $Z_{thJC} = f(t)$



Gate charge characteristic, IGBT, Inverter (typical) VGE = f(Qg) IC = 100A, Tv_j = 25°C

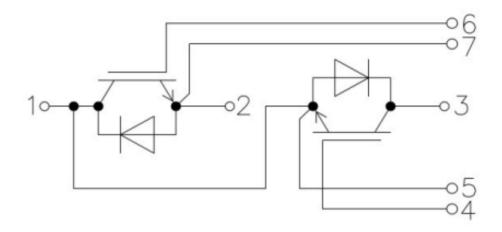




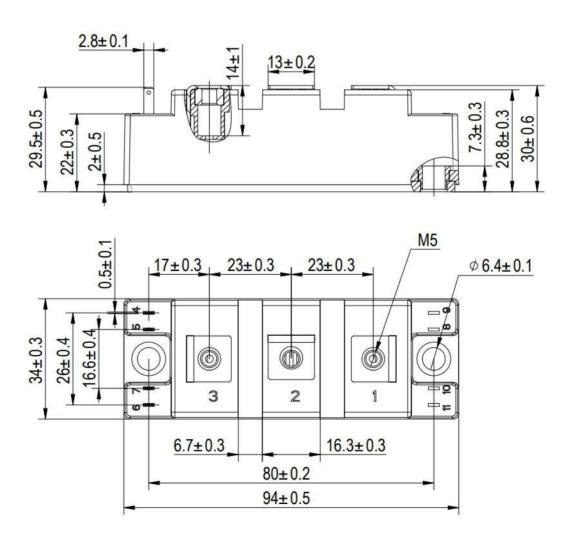




Internal Circuit



Package Dimension Dimensions in Millimeters





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